MC74VHCT74A

Dual D-Type Flip-Flop with Set and Reset

The MC74VHCT74A is an advanced high speed CMOS D−type flip−flop fabricated with silicon gate CMOS technology. It achieves high speed operation similar to equivalent Bipolar Schottky TTL while maintaining CMOS low power dissipation.

The signal level applied to the D input is transferred to Q output during the positive going transition of the Clock pulse.

Reset ($\overline{RD}$) and Set ($\overline{SD}$) are independent of the Clock (CP) and are accomplished by setting the appropriate input Low.

The internal circuit is composed of three stages, including a buffer output which provides high noise immunity and stable output. The inputs tolerate voltages up to 7.0 V, allowing the interface of 5.0 V systems to 3.0 V systems.

The VHCT inputs are compatible with TTL levels. This device can be used as a level converter for interfacing 3.3 V to 5.0 V, because it has full 5.0 V CMOS level output swings.

The VHCT74A input structures provide protection when voltages between 0 V and 5.5 V are applied, regardless of the supply voltage. The output structures also provide protection when V_{CC} = 0 V. These input and output structures help prevent device destruction caused by supply voltage − input/output voltage mismatch, battery backup, hot insertion, etc.

Features

- High Speed: f_{max} = 60 MHz (Typ) at V_{CC} = 5.0 V
- Low Power Dissipation: I_{CC} = 2 μA (Max) at T_A = 25°C
- Power Down Protection Provided on Inputs
- Balanced Propagation Delays
- Designed for 4.5 V to 5.5 V Operating Range
- Low Noise: V_{OLP} = 0.8 V (Max)
- Pin and Function Compatible with Other Standard Logic Families
- Latchup Performance Exceeds 300 mA
- ESD Performance: HBM > 2000 V; Machine Model > 200 V
- Chip Complexity: 128 FETs or 32 Equivalent Gates
- Pb−Free Packages are Available

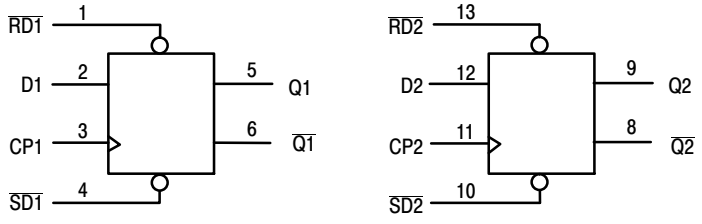
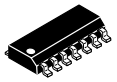


Figure 2. Logic Diagram

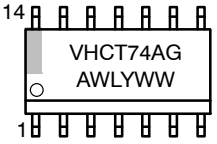
ON Semiconductor®

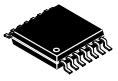
http://onsemi.com

MARKING DIAGRAMS

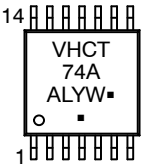


SOIC−14
D SUFFIX
CASE 751A





TSSOP−14
DT SUFFIX
CASE 948G



A = Assembly Location
WL, L = Wafer Lot
Y = Year
WW, W = Work Week
G or ▪ = Pb−Free Package
(Note: Microdot may be in either location)

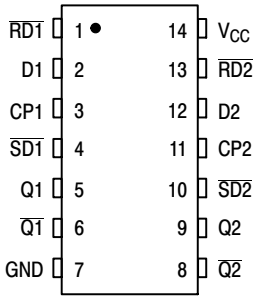


Figure 1. Pin Assignment

FUNCTION TABLE

Inputs				Outputs	
$\overline{SD}$	$\overline{RD}$	CP	D	Q	$\overline{Q}$
L	H	X	X	H	L
H	L	X	X	L	H
L	L	X	X	H*	H*
H	H	↑	H	H	L
H	H	↑	L	L	H
H	H	L	X	No Change	
H	H	H	X	No Change	
H	H	↓	X	No Change	

*Both outputs will remain high as long as Set and Reset are low, but the output states are unpredictable if Set and Reset go high simultaneously.

ORDERING INFORMATION

See detailed ordering and shipping information on page 3 of this data sheet.

© Semiconductor Components Industries, LLC, 2009

MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CC}	DC Supply Voltage	−0.5 to + 7.0	V
V_{in}	DC Input Voltage	−0.5 to + 7.0	V
V_{out}	DC Output Voltage V_{CC} = 0 High or Low State	−0.5 to + 7.0 −0.5 to V_{CC} + 0.5	V
I_{IK}	Input Diode Current	−20	mA
I_{OK}	Output Diode Current (V_{OUT} < GND; V_{OUT} > V_{CC})	±20	mA
I_{out}	DC Output Current, per Pin	±25	mA
I_{CC}	DC Supply Current, V_{CC} and GND Pins	±50	mA
P_D	Power Dissipation in Still Air, SOIC Packages† TSSOP Package†	500 450	mW
T_{stg}	Storage Temperature	−65 to + 150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

†Derating − SOIC Packages: − 7 mW/°C from 65° to 125°C
TSSOP Package: − 6.1 mW/°C from 65° to 125°C

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high−impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range GND ≤ (V_{in} or V_{out}) ≤ V_{CC}.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
V_{CC}	DC Supply Voltage	4.5	5.5	V
V_{in}	DC Input Voltage	0	5.5	V
V_{out}	DC Output Voltage V_{CC} = 0 High or Low State	0 0	5.5 V_{CC}	V
T_A	Operating Temperature	−55	+ 125	°C
t_r, t_f	Input Rise and Fall Time V_{CC} =5.0 V ± 0.5 V	0	20	ns/V

DC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Test Conditions	V_{CC} V	T_A = 25°C			T_A = − 55 to 125°C		Unit
				Min	Typ	Max	Min	Max	
V_{IH}	Minimum High−Level Input Voltage		4.5 to 5.5	2.0			2.0		V
V_{IL}	Maximum Low−Level Input Voltage		4.5 to 5.5			0.8		0.8	V
V_{OH}	Minimum High−Level Output Voltage V_{in} = V_{IH} or V_{IL}	I_{OH} = −50 μA	4.5	4.4	4.5		4.4		V
		I_{OH} = −8 mA	4.5	3.94			3.80		
V_{OL}	Maximum Low−Level Output Voltage V_{in} = V_{IH} or V_{IL}	I_{OL} = 50 μA	4.5		0.0	0.1		0.1	V
		I_{OL} = 8 mA	4.5			0.36		0.44	
I_{in}	Maximum Input Leakage Current	V_{in} = 5.5 V or GND	0 to 5.5			±0.1		±1.0	μA
I_{CC}	Maximum Quiescent Supply Current	V_{in} = V_{CC} or GND	5.5			2.0		20.0	μA
I_{CCT}	Quiescent Supply Current	Per Input: V_{IN} = 3.4 V Other Input: V_{CC} or GND	5.5			1.35		1.50	mA
I_{OPD}	Output Leakage Current	V_{OUT} = 5.5 V	0			0.5		5.0	μA

AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3.0$ns)

Symbol	Parameter	Test Conditions	T_A = 25°C			T_A = − 55 to 125°C		Unit
			Min	Typ	Max	Min	Max	
t_{PLH}, t_{PHL}	Maximum Propagation Delay, CP to Q or $\overline{Q}$	V_{CC} = 5.0 ± 0.5V C_L = 15 pF C_L = 50 pF		5.8 6.3	7.8 8.8	1.0 1.0	9.0 10.0	ns
t_{PLH}, t_{PHL}	Maximum Propagation Delay, $\overline{SD}$ or $\overline{RD}$ to Q or $\overline{Q}$	V_{CC} = 5.0 ± 0.5V C_L = 15 pF C_L = 50 pF		7.6 8.1	10.4 11.4	1.0 1.0	12.0 13.0	ns
f_{max}	Maximum Clock Frequency (50% Duty Cycle)	V_{CC} = 5.0 ± 0.5V C_L = 15 pF C_L = 50 pF	100 80	160 140		80 65		MHz
C_{in}	Maximum Input Capacitance			4	10		10	pF

		Typical @ 25°C, V_{CC} = 5.0 V	
C_{PD}	Power Dissipation Capacitance (Note 1)	24	pF

1. C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: $I_{CC(OPR)} = C_{PD} \bullet V_{CC} \bullet f_{in} + I_{CC}/2$ (per flip−flop). C_{PD} is used to determine the no−load dynamic power consumption; $P_D = C_{PD} \bullet V_{CC}^2 \bullet f_{in} + I_{CC} \bullet V_{CC}$.

TIMING REQUIREMENTS (Input $t_r = t_f = 3.0$ ns)

Symbol	Parameter	V_{CC} V	Guaranteed Limit		Unit
			T_A = 25°C	T_A = − 55 to 125°C	
t_w	Minimum Pulse Width, CP	5.0 ± 0.5	5.0	5.0	ns
t_w	Minimum Pulse Width, $\overline{RD}$ or $\overline{SD}$	5.0 ± 0.5	5.0	5.0	ns
t_{su}	Minimum Setup Time, D to CP	5.0 ± 0.5	5.0	5.0	ns
t_h	Minimum Hold Time, D to CP	5.0 ± 0.5	0.0	0.0	ns
t_{rec}	Minimum Recovery Time, $\overline{SD}$ or $\overline{RD}$ to CP	5.0 ± 0.5	3.5	3.5	ns

ORDERING INFORMATION

Device	Package	Shipping†
MC74VHCT74AD	SOIC−14	55 Units / Rail
MC74VHCT74ADR2	SOIC−14	2500 / Tape & Reel
MC74VHCT74ADR2G	SOIC−14 (Pb−Free)	2500 / Tape & Reel
MC74VHCT74ADT	TSSOP−14*	96 Units / Rail
MC74VHCT74ADTR2	TSSOP−14*	2500 / Tape & Reel
MC74VHCT74ADTR2G	TSSOP−14*	2500 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
*This package is inherently Pb−Free.

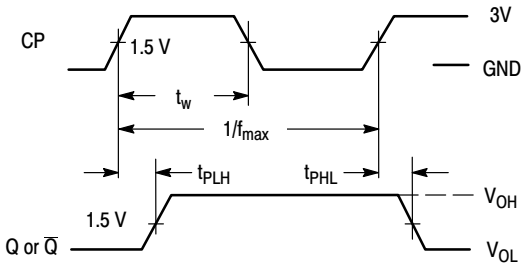


Figure 3. Switching Waveform

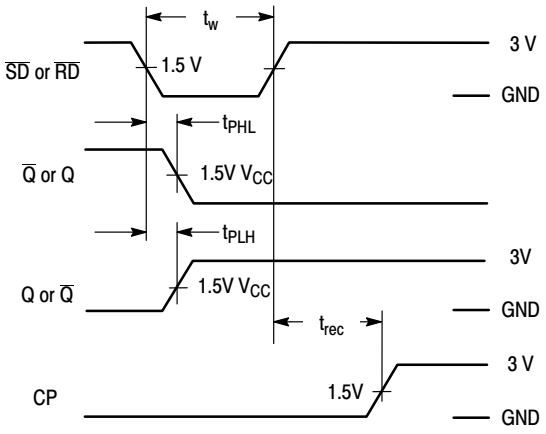


Figure 4. Switching Waveform

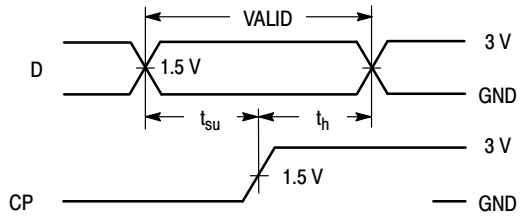
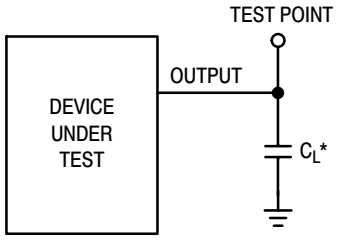


Figure 5. Switching Waveform



*Includes all probe and jig capacitance

Figure 6. Switching Waveform

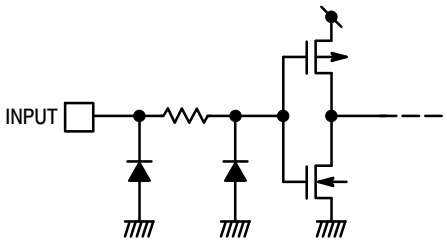
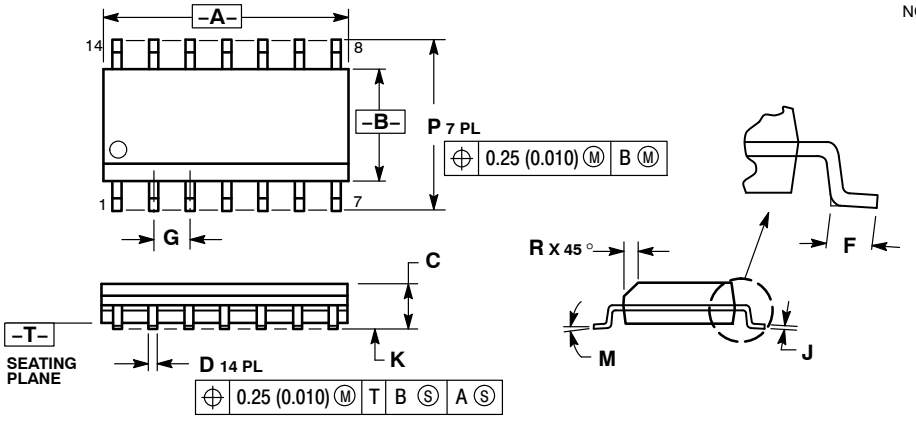


Figure 7. Input Equivalent Circuit

PACKAGE DIMENSIONS

SOIC−14
D SUFFIX
CASE 751A−03
ISSUE G

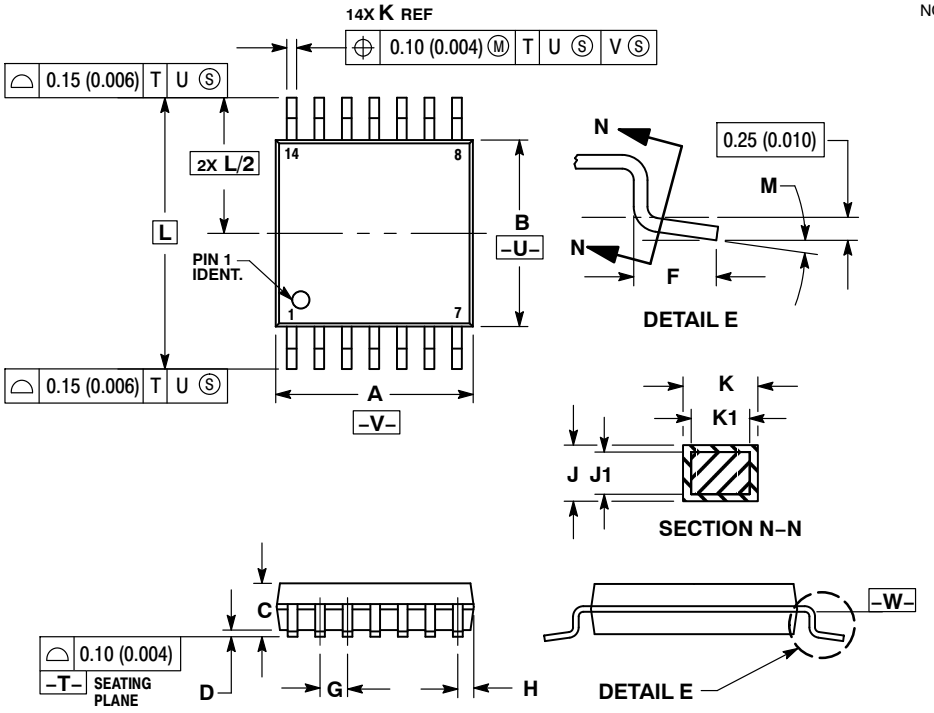


NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	8.55	8.75	0.337	0.344
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27 BSC		0.050 BSC	
J	0.19	0.25	0.008	0.009
K	0.10	0.25	0.004	0.009
M	0 °	7 °	0 °	7 °
P	5.80	6.20	0.228	0.244
R	0.25	0.50	0.010	0.019

PACKAGE DIMENSIONS

TSSOP−14
DT SUFFIX
CASE 948G−01
ISSUE A



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE −W−.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	4.90	5.10	0.193	0.200
B	4.30	4.50	0.169	0.177
C	−−−	1.20	−−−	0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65 BSC		0.026 BSC	
H	0.50	0.60	0.020	0.024
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40 BSC		0.252 BSC	
M	0 °	8 °	0 °	8 °

ON Semiconductor and ON are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. “Typical” parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including “Typicals” must be validated for each customer application by customer’s technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:
Literature Distribution Center for ON Semiconductor
P.O. Box 5163, Denver, Colorado 80217 USA
Phone: 303−675−2175 or 800−344−3860 Toll Free USA/Canada
Fax: 303−675−2176 or 800−344−3867 Toll Free USA/Canada
Email: orderlit@onsemi.com

N. American Technical Support: 800−282−9855 Toll Free USA/Canada
Europe, Middle East and Africa Technical Support:
Phone: 421 33 790 2910
Japan Customer Focus Center
Phone: 81−3−5773−3850

ON Semiconductor Website: **www.onsemi.com**

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative